# PBSS5220T

# 20 V, 2 A PNP low VCEsat transistor

1 July 2023

**Product data sheet** 

# 1. General description

PNP low V<sub>CEsat</sub> transistor in a SOT23 small Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability: I<sub>C</sub> and I<sub>CM</sub>
- · Higher efficiency leading to less heat generation

# 3. Applications

- DC-to-DC conversion
- · Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-3	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -2 A; $I_B$ = -200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	113	mΩ

# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	E	emitter		j
3	С	collector		В — (
			1 2	 E
			SOT23	sym013



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# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
PBSS5220T	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5220T	%3F

[1] % = placeholder for manufacturing site code

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-20	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-20	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	Α
I <sub>СМ</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-3	Α
I <sub>B</sub>	base current			-	-300	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uily-a)	thermal resistance from	in free air	[1]	-	-	417	K/W
	junction to ambient		[2]	-	-	260	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

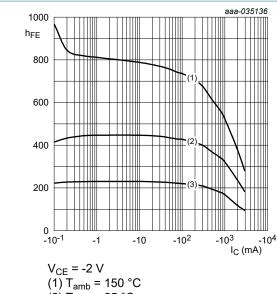
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# 10. Characteristics

#### **Table 7. Characteristics**

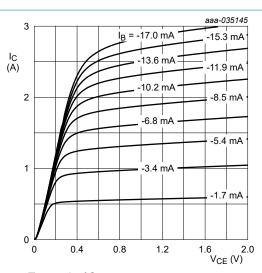
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -20 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -20 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -100 mA; T <sub>amb</sub> = 25 °C	225	-	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA; T <sub>amb</sub> = 25 °C	225	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -1 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	200	-	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -2 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	150	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -500 mA; $I_B$ = -50 mA; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_{amb}$ = 25 °C; pulsed	-	-	-80	mV
		$I_C$ = -1 A; $I_B$ = -50 mA; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_{amb}$ = 25 °C; pulsed	-	-	-150	mV
		$I_C$ = -2 A; $I_B$ = -100 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	-250	mV
		$I_C$ = -2 A; $I_B$ = -200 mA; pulsed; $t_p \le$	-	-	-225	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	-	113	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -2 A; $I_B$ = -100 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	-1.1	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE}$ = -2 V; $I_{C}$ = -1 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-1.2	-	-	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -100 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	-	50	pF

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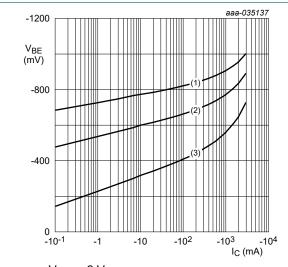
(2)  $T_{amb} = 25 \text{ °C}$ (3)  $T_{amb} = -55 \text{ °C}$ 

Fig. 1. DC current gain as a function of collector current; typical values



 $T_{amb}$  = 25 °C

Fig. 2. Collector current as a function of collectoremitter voltage; typical values

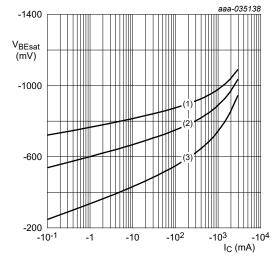


 $V_{CE} = -2 V$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \,^{\circ}\text{C}$ (3)  $T_{amb} = 150 \,^{\circ}\text{C}$ 

Fig. 3. Base-emitter voltage as a function of collector current; typical values



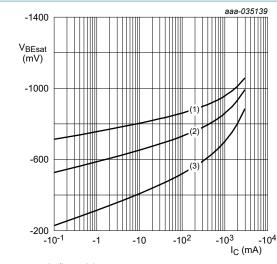
 $I_{\rm C}/I_{\rm B} = 10$ 

(1) T<sub>amb</sub> = -55 °C (2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = 150 \, ^{\circ}C$ 

Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

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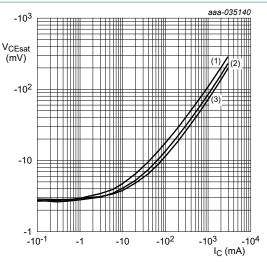
$$I_{\rm C}/I_{\rm B} = 20$$

$$I_{\rm C}/I_{\rm B} = 20$$
 (1)  $T_{\rm amb} = -55 \,^{\circ}{\rm C}$ 

(2) 
$$T_{amb} = 25 \,^{\circ}\text{C}$$
  
(3)  $T_{amb} = 150 \,^{\circ}\text{C}$ 

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Base-emitter saturation voltage as a function of Fig. 6. collector current; typical values

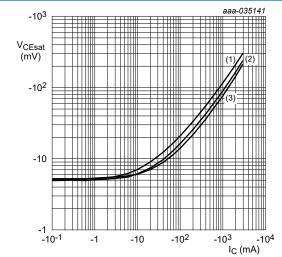


$$I_{\rm C}/I_{\rm B} = 10$$

$$I_{C}/I_{B} = 10$$
  
(1)  $T_{amb} = 150 \,^{\circ}C$ 

(2) 
$$T_{amb} = 25 \,^{\circ}C$$
  
(3)  $T_{amb} = -55 \,^{\circ}C$ 

Collector-emitter saturation voltage as a function of collector current; typical values



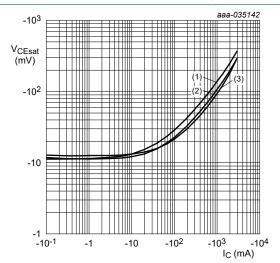
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

$$(2) T_{omb} = 25 ^{\circ}C$$

(1) 
$$T_{amb} = 150^{\circ} \text{ C}$$
  
(2)  $T_{amb} = 25^{\circ} \text{ C}$   
(3)  $T_{amb} = -55^{\circ} \text{ C}$ 

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



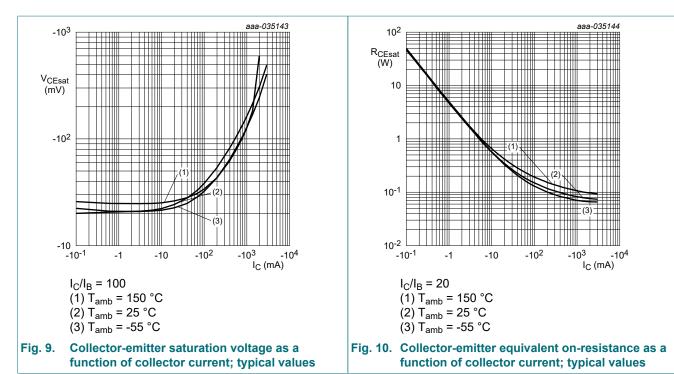
$$I_{\rm C}/I_{\rm B} = 50$$

$$(2) T_{amb} = 25 ^{\circ}C$$

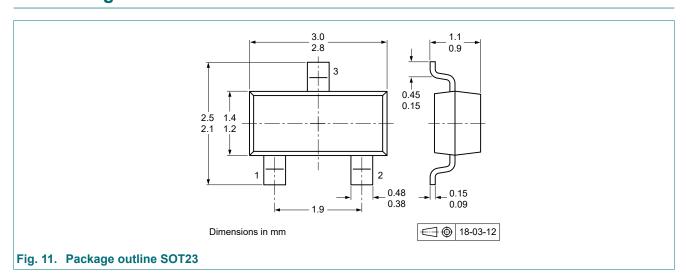
(3) 
$$T_{amb} = -55 \,^{\circ}C$$

Collector-emitter saturation voltage as a Fig. 8. function of collector current; typical values

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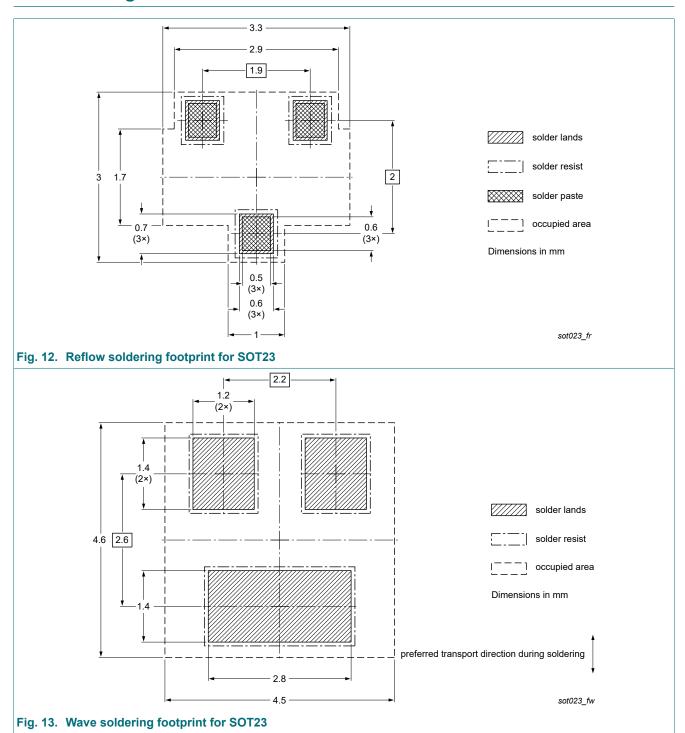


# 11. Package outline



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# 12. Soldering



### 20 V, 2 A PNP low VCEsat transistor

# 13. Revision history

#### **Table 8. Revision history**

Table of Reviews							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS5220T v.3	20230701	Product data sheet	-	PBSS5220T v.2			
Modifications:	<ul> <li>Product changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).</li> <li>Characteristics: Figures 1 - 10 added</li> </ul>						
PBSS5220T v.2	20220524	Product data sheet	-	PBSS5220T v.1			
PBSS5220T v.1	20031218	Product data sheet	-	-			

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#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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